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## B.Tech II Year II Semester (R09) Supplementary Examinations May/June 2017

## ANALOG ELECTRONIC CIRCUITS

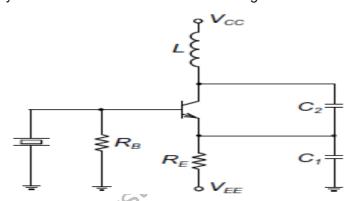
(Electrical & Electronics Engineering)

Time: 3 hours Max. Marks: 70

## Answer any FIVE questions All questions carry equal marks

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- 1 Derive all components in the Hybrid- $\pi$  model in terms of h-parameters in CE configuration.
- 2 (a) What is diffusion capacitance of a transistor and derive its equation.
  - (b) In a given germanium PNP transistor, base width is 10<sup>-4</sup> cm. At room temperature and for a dc emitter current of 2mA, find emitter diffusion capacitance and gain-band width product.
- 3 (a) Classify the feedback amplifiers and draw block diagrams.
  - (b) The open loop gain of an amplifier is 50 and its output impedance is 40 k $\Omega$ . When a negative feedback is applied, the output impedance becomes 6.666 k $\Omega$ . Find the feedback factor.
- 4 Derive the frequency of oscillations of the circuit shown in figure.



- 5 (a) Write short notes on requirement and types of heat sinks for power dissipation in large signal amplifiers.
  - (b) With the help of a neat circuit diagram, explain the operation of a complementary symmetry configured class-B power amplifier.
  - (c) Compare and contrast push-pull and complementary-symmetry configurations for class-B power amplifiers.
- 6 (a) What is synchronized clamping? Explain.
  - (b) Design a diode clamper circuit to clamp the positive peaks of the input signal at zero level. The frequency of the input signal is 500 Hz.
- 7 (a) Explain the reverse recovers of a semiconductor diode. How does the recovery time place a limitation on the diode speed?
  - (b) Write about diode switching times.
- 8 Calculate the stable state currents and voltages for the self biased bistable multivibrator which uses n-p-n silicon transistors. The various parameters for the circuit are:  $V_{cc}$  = 12 V,  $R_1$  = 30 kΩ,  $R_c$  = 4 kΩ,  $R_2$  = 10 kΩ and  $R_E$  = 500 Ω.